

Hui Sun

List of Publications by Year in descending order

Source: <https://exaly.com/author-pdf/5207797/publications.pdf>

Version: 2024-02-01

47
papers

665
citations

471509

17
h-index

677142

22
g-index

47
all docs

47
docs citations

47
times ranked

658
citing authors

#	ARTICLE	IF	CITATIONS
1	Effect of annealing temperature on the optoelectronic properties and structure of NiO films. <i>Ceramics International</i> , 2022, 48, 2820-2825.	4.8	18
2	Highly transparent and conductive p-type CuI films by optimized solid-iodination at room temperature. <i>Nanotechnology</i> , 2022, 33, 105706.	2.6	6
3	High power impulse magnetron sputtering growth processes for copper nitride thin film and its highly enhanced UV - visible photodetection properties. <i>Journal of Alloys and Compounds</i> , 2022, 896, 162924.	5.5	8
4	Periodic mesoporous organosilica coupled with chlorin e6 and catalase for enhanced photodynamic therapy to treat triple-negative breast cancer. <i>Journal of Colloid and Interface Science</i> , 2022, 610, 634-642.	9.4	8
5	Pico-molar level detection of copper ion with extraordinarily high response by Ti-doped copper nitride fabricated via high power impulse magnetron sputtering. <i>Sensors and Actuators B: Chemical</i> , 2022, 360, 131632.	7.8	3
6	Research Progress of p-Type Oxide Thin-Film Transistors. <i>Materials</i> , 2022, 15, 4781.	2.9	11
7	Review in optoelectronic properties of p-type CuCrO ₂ transparent conductive films. <i>Surfaces and Interfaces</i> , 2021, 22, 100824.	3.0	18
8	Optoelectronic properties of an AZO/Ag multilayer employed as a flexible electrode. <i>Ceramics International</i> , 2021, 47, 5671-5676.	4.8	19
9	Influence of carbon content on the mechanical properties of TiCN@Cu nanocomposite coatings prepared by multi-arc ion plating. <i>Vacuum</i> , 2021, 187, 110139.	3.5	18
10	Tuning the Electrical Properties of NiO Thin Films by Stoichiometry and Microstructure. <i>Coatings</i> , 2021, 11, 697.	2.6	1
11	Influence of annealing temperature on the optoelectronic properties of ITZO thin films. <i>Nanotechnology</i> , 2021, 32, 405701.	2.6	2
12	Research Progress of Transparent Electrode Materials with Sandwich Structure. <i>Materials</i> , 2021, 14, 4097.	2.9	6
13	In-Sn-Zn Oxide Nanocomposite Films with Enhanced Electrical Properties Deposited by High-Power Impulse Magnetron Sputtering. <i>Nanomaterials</i> , 2021, 11, 2016.	4.1	4
14	Optoelectronic properties of p-type NiO films deposited by direct current magnetron sputtering versus high power impulse magnetron sputtering. <i>Applied Surface Science</i> , 2020, 508, 145106.	6.1	30
15	Structure, mechanical and tribological properties, and oxidation resistance of TaC/a-C:H films deposited by high power impulse magnetron sputtering. <i>Ceramics International</i> , 2020, 46, 24986-25000.	4.8	14
16	Mechanical properties, thermal stability and oxidation resistance of HfC/a-C:H films deposited by HiPIMS. <i>Journal of Alloys and Compounds</i> , 2020, 847, 156538.	5.5	10
17	p-type semi-transparent conductive NiO films with high deposition rate produced by superimposed high power impulse magnetron sputtering. <i>Ceramics International</i> , 2020, 46, 27695-27701.	4.8	10
18	Transparent Conductive p-Type Cuprous Oxide Films in Vis-NIR Region Prepared by Ion-Beam Assisted DC Reactive Sputtering. <i>Coatings</i> , 2020, 10, 473.	2.6	9

#	ARTICLE	IF	CITATIONS
19	The Optoelectronic Properties of p-Type Cr-Deficient Cu[Cr _{0.95} xMg _{0.05}]O ₂ Films Deposited by Reactive Magnetron Sputtering. <i>Materials</i> , 2020, 13, 2376.	2.9	6
20	Research on adhesion strength and optical properties of SiC films obtained via RF magnetron sputtering. <i>Chinese Journal of Physics</i> , 2020, 64, 79-86.	3.9	10
21	Influence of power frequency on the performance of SiC thin films deposited by pulsed DC magnetron sputtering. <i>Journal of Adhesion Science and Technology</i> , 2019, 33, 2181-2190.	2.6	7
22	Influence of Sputtering Power on the Electrical Properties of In-Sn-Zn Oxide Thin Films Deposited by High Power Impulse Magnetron Sputtering. <i>Coatings</i> , 2019, 9, 715.	2.6	6
23	Contribution of enhanced ionization to the optoelectronic properties of p-type NiO films deposited by high power impulse magnetron sputtering. <i>Journal of the European Ceramic Society</i> , 2019, 39, 5285-5291.	5.7	17
24	Comparison of microstructural and optoelectronic properties of NiO:Cu thin films deposited by ion-beam assisted rf sputtering in different gas atmospheres. <i>Thin Solid Films</i> , 2019, 677, 103-108.	1.8	8
25	Optoelectronic properties of Cu ₃ N thin films deposited by reactive magnetron sputtering and its diode rectification characteristics. <i>Journal of Alloys and Compounds</i> , 2019, 789, 428-434.	5.5	29
26	Enhanced photocatalytic activity by photo-Fenton reaction: towards TiO ₂ nanotubes sensitized by Fe(III)-tartrate. <i>Journal Physics D: Applied Physics</i> , 2019, 52, 175302.	2.8	2
27	Light enhanced moisture degradation of perovskite solar cell material CH ₃ NH ₃ PbI ₃ . <i>Journal of Materials Chemistry A</i> , 2019, 7, 27469-27474.	10.3	37
28	Electrical and magnetic properties of (Al, Co) co-doped ZnO films deposited by RF magnetron sputtering. <i>Surface and Coatings Technology</i> , 2019, 359, 390-395.	4.8	20
29	The adhesion strength and mechanical properties of SiC films deposited on SiAlON buffer layer by magnetron sputtering. <i>Surface and Coatings Technology</i> , 2019, 360, 116-120.	4.8	10
30	Synthesis and characterization of n-type NiO:Al thin films for fabrication of p-n NiO homojunctions. <i>Journal Physics D: Applied Physics</i> , 2018, 51, 105109.	2.8	13
31	High transmittance in IR region of conductive ITO/AZO multilayers deposited by RF magnetron sputtering. <i>Ceramics International</i> , 2018, 44, 6769-6774.	4.8	27
32	Impact of active layer thickness of nitrogen-doped In ₂ Sn ₂ Zn ₂ O films on materials and thin film transistor performances. <i>Journal Physics D: Applied Physics</i> , 2018, 51, 175101.	2.8	13
33	p-type conductive NiOx: Cu thin films with high carrier mobility deposited by ion beam assisted deposition. <i>Ceramics International</i> , 2018, 44, 3291-3296.	4.8	18
34	The Influence of Oxygen Flow Ratio on the Optoelectronic Properties of p-Type Ni _{1-x} O Films Deposited by Ion Beam Assisted Sputtering. <i>Coatings</i> , 2018, 8, 168.	2.6	12
35	p-type cuprous oxide thin films with high conductivity deposited by high power impulse magnetron sputtering. <i>Ceramics International</i> , 2017, 43, 6214-6220.	4.8	25
36	Microstructures and optoelectronic properties of nickel oxide films deposited by reactive magnetron sputtering at various working pressures of pure oxygen environment. <i>Ceramics International</i> , 2017, 43, S369-S375.	4.8	30

#	ARTICLE	IF	CITATIONS
37	Thickness-dependent optoelectronic properties of CuCr _{0.93} Mg _{0.07} O ₂ thin films deposited by reactive magnetron sputtering. <i>Materials Science in Semiconductor Processing</i> , 2017, 63, 295-302.	4.0	12
38	The electrical stability of In-doped ZnO thin films deposited by RF sputtering. <i>Journal Physics D: Applied Physics</i> , 2017, 50, 045102.	2.8	10
39	Ag composition gradient CuCr _{0.93} Mg _{0.07} O ₂ /Ag/CuCr _{0.93} Mg _{0.07} O ₂ coatings with improved p-type optoelectronic performances. <i>Journal of Materials Science</i> , 2017, 52, 11537-11546.	3.7	14
40	Absorption Amelioration of Amorphous Si Film by Introducing Metal Silicide Nanoparticles. <i>Nanoscale Research Letters</i> , 2017, 12, 224.	5.7	5
41	High photodegradation ability of dyes by Fe(III)-tartrate/TiO ₂ nanotubular photocatalyst supported via photo-Fenton reaction. <i>Journal of Photochemistry and Photobiology A: Chemistry</i> , 2017, 334, 20-25.	3.9	18
42	Optoelectronic Properties and the Electrical Stability of Ga-Doped ZnO Thin Films Prepared via Radio Frequency Sputtering. <i>Materials</i> , 2016, 9, 987.	2.9	14
43	Optoelectronic properties of delafossite structure CuCr _{0.93} Mg _{0.07} O ₂ sputter deposited coatings. <i>Journal Physics D: Applied Physics</i> , 2016, 49, 185105.	2.8	26
44	Microstructures and optoelectronic properties of Cu _x O films deposited by high-power impulse magnetron sputtering. <i>Journal of Alloys and Compounds</i> , 2016, 688, 672-678.	5.5	22
45	Towards delafossite structure of CuCrO thin films deposited by reactive magnetron sputtering: Influence of substrate temperature on optoelectronics properties. <i>Vacuum</i> , 2015, 114, 101-107.	3.5	22
46	Modification of TiO ₂ nanotubes by WO ₃ species for improving their photocatalytic activity. <i>Applied Surface Science</i> , 2015, 343, 181-187.	6.1	37
47	Design of flexible resistance sensor based on mesh convex microstructure. <i>Journal Physics D: Applied Physics</i> , 0, , .	2.8	0